## **Abstract Submission Instructions**

Abstracts must be submitted by **April 23, 2018 extended deadline April 30**, 2018. Revisions will only be accepted until the abstract submission deadline. Papers will be selected by the Technical Program Committee based upon technical content and novelty. Authors will be notified by email in June 2018 regarding the status of their paper. Notifications are sent only to the presenting author and corresponding author.

Abstracts MUST be prepared using instructions and format described in the <u>Abstract Template</u>. The abstracts must be submitted ONLY online. The only accepted format is Acrobat PDF. Please do not password protect your PDF file. After submission, a confirmation email will be sent.

## Download Abstract Template

Extended abstracts must be submitted under one of the following topics:

- 1 Fundamentals (theoretical and experimental)
- 2 Bulk and Epitaxial Growth
- 3 New Materials Grown on SiC (Graphene, III-N compounds, and diamond)
- 4 Materials Characterization
- 5 Surfaces and Interfaces
- 6 Device Fabrication Processes
- 7 Devices (power switching, RF power, high-temperature and radiation-resistant devices and sensors, etc.)
- 8 Device physics (measurements, modelling, simulation and reliability)
- 9 Packaging, Modular and Circuit Technology
- 10 Applications and reliability
- 11 Related materials

## **Late News Abstracts**

Late news abstract submission will open in early July. A limited number of late news abstracts will be accepted for poster presentation at the conference. The percentage of abstracts selected for late news presentation will depend on the number of submissions, but selection will be more rigorous than for regular abstracts. The same submission guidelines (template, topics, etc.) apply for late news abstracts as for regular abstracts, but **each presenting author may only submit one late news abstract**. The deadline for late news abstract submission is **July 24**, **2018**. The corresponding authors will be notified by email by 6 August 2018 regarding the status of their late news abstract.